## Product Preview

# Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low  $V_F = 0.60 \text{ V}$  at  $I_F = 10 \text{ A}$ 

## **Features**

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These Devices are Pb-Free and Halogen Free/BFR Free

## **Typical Applications**

- Switching Power Supplies including Telecom AC to DC Power Stages
- High Voltage DC-DC Converters
- Freewheeling and OR-ing Diodes
- Output Rectifier in Welding Power Supplies
- Industrial Automation

## **Mechanical Characteristics**

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec

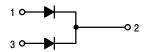


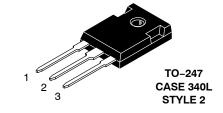
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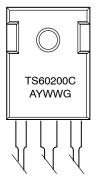
VERY LOW FORWARD
VOLTAGE, LOW LEAKAGE
SCHOTTKY BARRIER
RECTIFIERS 60 AMPERES,
200 VOLTS

#### **PIN CONNECTIONS**





## **MARKING DIAGRAM**



A = Assembly Location

Y = Year WW = Work Week

G = Pb-Free Package

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

## ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	V
Average Rectified Forward Current (Rated $V_R$ , $T_C$ = 112°C) Per device (Rated $V_R$ , $T_C$ = 133°C) Per diode	I <sub>F(AV)</sub>	60 30	Α
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz, $T_C$ = 115°C) Per device (Rated $V_R$ , Square Wave, 20 kHz, $T_C$ = 128°C) Per diode	I <sub>FRM</sub>	120 60	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	300	А
Operating Junction Temperature	TJ	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Rating		Value	Unit
Typical Thermal Resistance  Junction-to-Case Per Diode  Junction-to-Case Per Device	$R_{ heta JC}$	0.72 0.63	°C/W
Junction-to-Ambient Per Diode Junction-to-Ambient Per Device	$R_{ hetaJA}$	40.62 40.17	

## **ELECTRICAL CHARACTERISTICS** (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Instantaneous Forward Voltage (Note 1)	V <sub>F</sub>			V
$(I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$ $(I_F = 15 \text{ A}, T_J = 25^{\circ}\text{C})$		0.74 0.79	-	
(I <sub>F</sub> = 13 A, I <sub>J</sub> = 25 °C) (I <sub>F</sub> = 30 A, T <sub>J</sub> = 25 °C)		1.04	1.90	
$(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$ $(I_F = 15 \text{ A}, T_J = 125^{\circ}\text{C})$ $(I_F = 30\text{A}, T_J = 125^{\circ}\text{C})$		0.60 0.64 0.74	- - 0.85	
Instantaneous Reverse Current (Note 1) $(V_R = 180 \text{ V}, T_J = 25^{\circ}\text{C})$ (Rated dc Voltage, $T_J = 25^{\circ}\text{C})$	I <sub>R</sub>	3 5	- 100	μ <b>Α</b> μ <b>Α</b>
$(V_R = 180 \text{ V}, T_J = 125^{\circ}\text{C})$ (Rated dc Voltage, $T_J = 125^{\circ}\text{C}$ )		5.3 7	- 30	mA mA

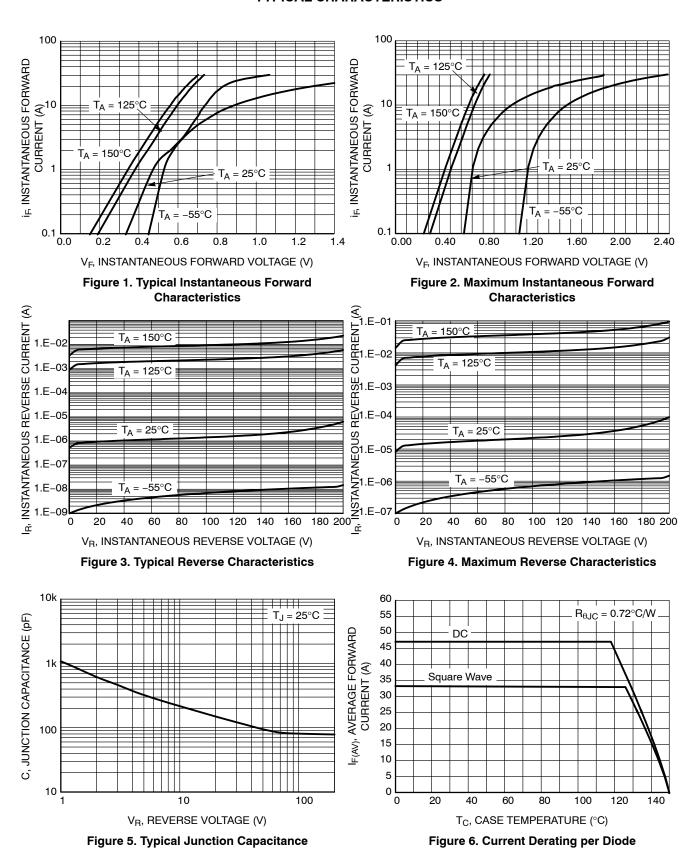
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **ORDERING INFORMATION**

Device	Package	Shipping
NTSW60200CTG	TO-220AB (Pb-Free, Halide Free)	30 Units / Rail

<sup>1.</sup> Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

## **TYPICAL CHARACTERISTICS**



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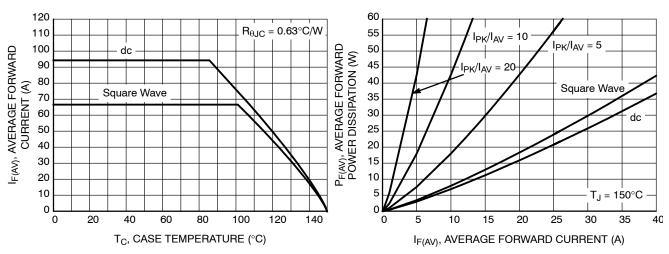


Figure 7. Current Derating per Device

Figure 8. Forward Power Dissipation

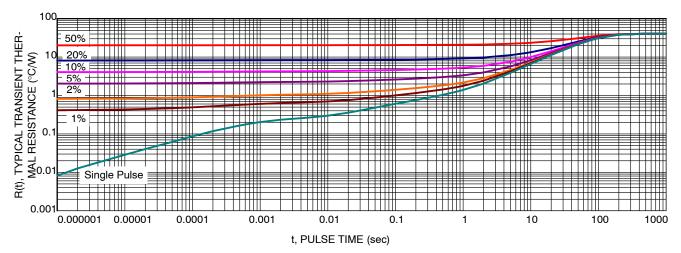
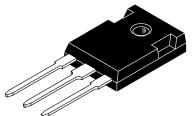


Figure 9. Typical Transient Thermal Response





3X D

**⊕** 0.25 (0.010)**W** Y AS

TO-247 CASE 340L ISSUE G

**DATE 06 OCT 2021** 

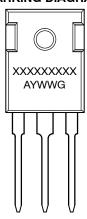
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER

	MILLIMETERS		INC	INCHES	
DIM	MIN.	MAX.	MIN.	MAX.	
Α	20.32	21.08	0.800	0.830	
В	15.75	16.26	0.620	0.640	
С	4.70	5.30	0.185	0.209	
D	1.00	1.40	0.040	0.055	
E	1.90	2.60	0.075	0.102	
F	1.65	2.13	0.065	0.084	
G	5.45 BSC		0.215 BSC		
Н	1.50	2.49	0.059	0.098	
J	0.40	0.80	0.016	0.031	
К	19.81	20.83	0.780	0.820	
L	5.40	6.20	0.212	0.244	
N	4.32	5.49	0.170	0.216	
Р		4.50		0.177	
Q	3.55	3.65	0.140	0.144	
U	6.15 BSC		0.242	0.242 BSC	
W	2.87	3.12	0.113	0.123	

# SCALE 1:1 Α øΩ 2X F

## **GENERIC MARKING DIAGRAM\***



STYLE 1:	
PIN 1.	GATE
2.	DRAIN
3.	SOURCE
4.	DRAIN

PIN 1. CATHODE

STYLE 5:

STYLE 2: PIN 1. ANODE 2. CATHODE (S) 3. ANODE 2 4. CATHODES (S)

STYLE 6:

STYLE 3: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR STYLE 4: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

XXXXX = Specific Device Code Α = Assembly Location

Υ = Year WW = Work Week = Pb-Free Package

PIN 1. MAIN TERMINAL 1 2. MAIN TERMINAL 2 2. ANODE \*This information is generic. Please refer to 3. GATE 4. ANODE 3. GATE 4. MAIN TERMINAL 2 device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

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